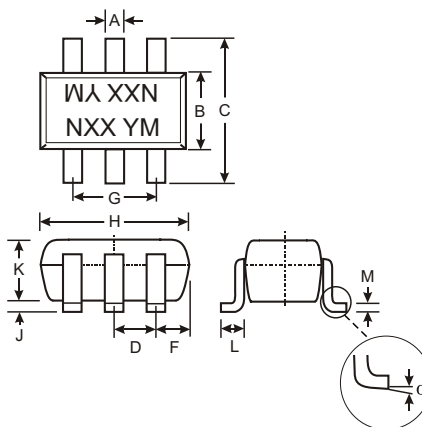


### Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- Lead-Free Device

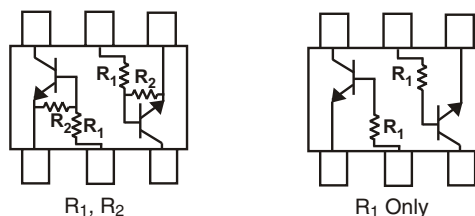
### Mechanical Data

- Case: SOT-363, Molded Plastic
- Moisture sensitivity: Level 1 per J-STD-020A
- Case material - UL Flammability Rating 94V-0
- Terminals: Finish - Matte Tin Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 2)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
$\alpha$	0°	8°
All Dimensions in mm		

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDC122LU	0.22K	10K	N81
DDC142JU	0.47K	10K	N82
DDC122TU	0.22K	OPEN	N83
DDC142TU	0.47K	OPEN	N84



SCHMATIC DIAGRAM

### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	V <sub>CC</sub>	50	V
Input Voltage	V <sub>IN</sub>	-5 to +6	V
Input Voltage	V <sub>EBO (MAX)</sub>	-5 to +6	V
Output Current	I <sub>C</sub>	100	mA
Power Dissipation (Note 3)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	R <sub>θJA</sub>	625	°C/W
Operating and Storage and Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

- Note:
1. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.
  2. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
  3. 150mW per element must not be exceeded.

**Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified **R1, R2 Types**

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDC122LU DDC142JU	V <sub>I(off)</sub>	0.3 0.3	—	—	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
	DDC122LU DDC142JU	V <sub>I(on)</sub>	—	—	2.0 2.0	V	V <sub>O</sub> = 0.3V, I <sub>O</sub> = 20mA V <sub>O</sub> = 0.3V, I <sub>O</sub> = 20mA
Output Voltage		V <sub>O(on)</sub>	—	—	0.3V	V	I <sub>O</sub> /I <sub>I</sub> = 5mA/0.25mA
Input Current	DDC122LU DDC142JU	I <sub>I</sub>	—	—	28 13	mA	V <sub>I</sub> = 5V
Output Current		I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	DDC122LU DDC142JU	G <sub>I</sub>	56 56	—	—	—	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
Gain-Bandwidth Product*		f <sub>T</sub>	—	200	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

\* Transistor - For Reference Only

**Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified **R1-Only**

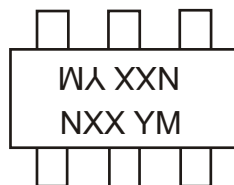
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	50	—	—	V	I <sub>C</sub> = 50μA
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	40	—	—	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	DDC122TU DDC142TU	BV <sub>EBO</sub>	5	—	—	V	I <sub>E</sub> = 50μA I <sub>E</sub> = 50μA
Collector Cutoff Current		I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 50V
Emitter Cutoff Current	DDC122TU DDC142TU	I <sub>EBO</sub>	—	—	0.5 0.5	μA	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	—	—	0.3	V	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA
DC Current Transfer Ratio	DDC122TU DDC142TU	h <sub>FE</sub>	100 100	250 250	600 600	—	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V
Gain-Bandwidth Product*		f <sub>T</sub>	—	200	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

\* Transistor - For Reference Only

**Ordering Information** (Note 4)

Device	Packaging	Shipping
DDC122LU-7	SOT-363	3000/Tape & Reel
DDC142JU-7	SOT-363	3000/Tape & Reel
DDC122TU-7	SOT-363	3000/Tape & Reel
DDC142TU-7	SOT-363	3000/Tape & Reel

- Notes: 1. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.  
4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**


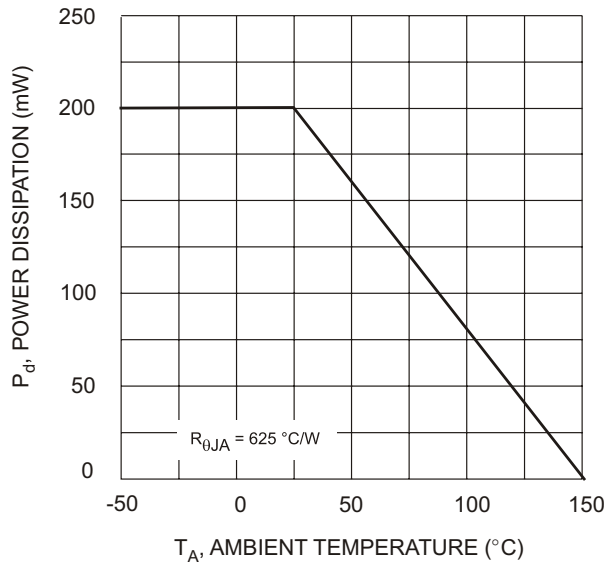
NXX = Product Type Marking Code  
See Sheet 1 Diagrams  
YM = Date Code Marking  
Y = Year ex: N = 2002  
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D



$T_A$ , AMBIENT TEMPERATURE (°C)  
Fig. 1 Power Derating Curve

(150mW per element must not be exceeded).



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.